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## VS-2EYH01HM3, VS-2EYH02HM3

### **Vishay Semiconductors**

### Hyperfast Rectifier, 2 A FRED Pt<sup>®</sup>



### **DESIGN SUPPORT TOOLS AVAILABLE**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 A			
V <sub>R</sub>	100 V, 200 V			
V <sub>F</sub> at I <sub>F</sub>	0.69 V			
I <sub>FSM</sub>	60 A			
t <sub>rr</sub> (typ.)	15 ns			
T <sub>J</sub> max.	175 °C			
Package	SlimSMAW (DO-221AD)			
Circuit configuration	Single			

#### **FEATURES**

- Low profile package
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, class 2 whisker test
- Compatible to SOD-128 package case outline
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial, and automotive applications.

#### **MECHANICAL DATA**

**Case:** SlimSMAW (DO-221AD) Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Polarity: color band denotes the cathode end

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse	VS-2EYH01HM3	V		100	V		
voltage	VS-2EYH02HM3	V <sub>RRM</sub>		200	v		
Average rectified forward current		I <sub>F(AV)</sub> <sup>(1)</sup>	T <sub>C</sub> = 151 °C	2	А		
Non-repetitive peak surge current		I <sub>FSM</sub>	$T_J = 25 \ ^{\circ}C$ , 10 ms sine pulse wave	60			
Operating junction and storage temperatures		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

#### Note

<sup>(1)</sup> Mounted on infinite heatsink

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS		
Breakdown voltage, blocking VS-2EYH01HM3	V V	L = 100 mA	100	-	-	V		
voltage VS-2EYH02HM3	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	200	-	-			
Forward voltage, per diade	V <sub>F</sub>	I <sub>F</sub> = 2 A	-	0.86	0.93			
Forward voltage, per diode		I <sub>F</sub> = 2 A, T <sub>J</sub> = 150 °C	-	0.69	0.75			
Reverse leakage current, per diode	I	$V_{R} = V_{R}$ rated	-	-	2	uА		
neverse leakage current, per diode	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	20	μΑ		
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	12	-	pF		

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RoHS

COMPLIANT HALOGEN

FREE



### **Vishay Semiconductors**

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	= 50 A/µs, V <sub>R</sub> = 30 V	-	22	-	
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	100 A/µs, V <sub>R</sub> = 30 V	-	15	-	
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1A, I <sub>rr</sub> = 0.25 A		-	-	28	ns
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 2 A, dI <sub>F</sub> /dt = 200 A/μs, V <sub>R</sub> = 100 V	-	16	-	-
		T <sub>J</sub> = 125 °C		-	26	-	
Deels receiver a current		T <sub>J</sub> = 25 °C		-	2.7	-	•
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C		-	3.4	-	A
	0	T <sub>J</sub> = 25 °C		-	20	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	43	-	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and stora	ge temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C	
Thermal resistance, junction to mount		R <sub>thJM</sub> <sup>(1)</sup>	Infinite heatsink	-	12	15		
Thermal resistance, junction to ambient		R <sub>thJA</sub>	Device mounted on FR4 PCB, 2 oz. standard footprint	-	120	150	°C/W	
VS-2EYH01HM3			Case style SlimSMAW (DO-221AD)	2H1				
Marking device	VS-2EYH02HM3		Case style SimiSiviAW (DO-22 TAD)	2H2				

#### Note

<sup>(1)</sup> Thermal resistance junction to mount follows JEDEC<sup>®</sup> 51-14 transient dual interface test method (TDIM)

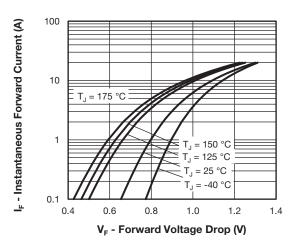


Fig. 1 - Typical Forward Voltage Drop Characteristics

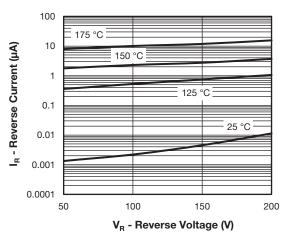


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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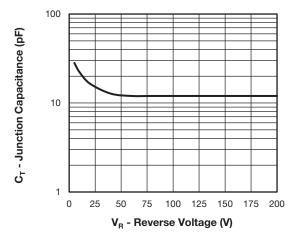


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

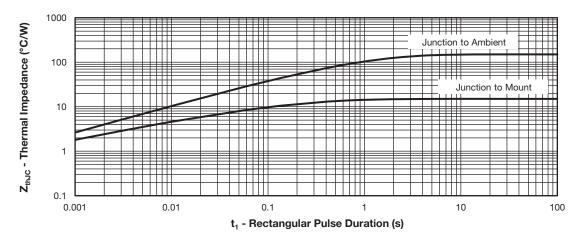
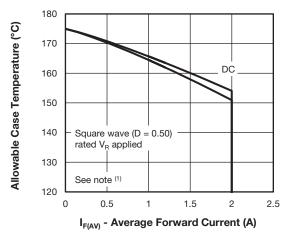
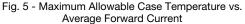


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics







<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

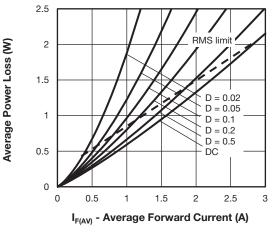


Fig. 6 - Forward Power Loss Characteristics

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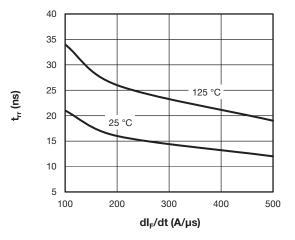
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Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

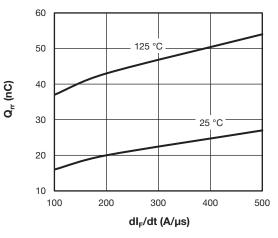


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

### **ORDERING INFORMATION TABLE**

Device code	vs-	2	Е	Y	н	02	н	M3
·	1	2	3	4	5	6	7	8
	1 · 2 ·	Cur	rent rati	nicondu ng (2 =	2 A)	oduct		
	3 -		uit conf single c	iguration liode	า:			
	4 -			1AW (D0	D-221AI	D)		
Í	5 -	Pro	cess typ	De,				
	_			ast recov	-			
	6 -	Vol	age coo	de (02 =	200 V)			
	7 -	H =	AEC-Q	101 qua	lified			
	8 -	M3	= halog	en-free,	RoHS-	complia	nt, and	termina

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-2EYH01HM3/H	0.033	н	3500	7"diameter plastic tape and reel				
VS-2EYH01HM3/I	0.033	I	14 000	13"diameter plastic tape and reel				
VS-2EYH02HM3/H	0.033	Н	3500	7"diameter plastic tape and reel				
VS-2EYH02HM3/I	0.033	I	14 000	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96582				
Part marking information	www.vishay.com/doc?95562				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96585				

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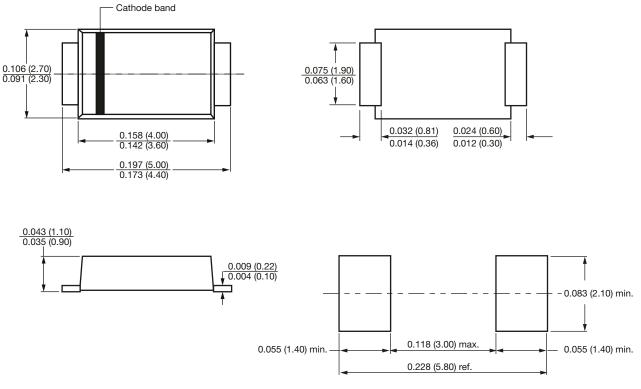
### **Outline Dimensions**

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## SlimSMAW (DO-221AD)

### **DIMENSIONS** in inches (millimeters)

SlimSMAW (DO-221AD)



Mounting pad layout





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